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HMC853* Product Page Quick Links

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Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC853LC3 Evaluation Board

Documentation

Data Sheet

- HMC853 Data Sheet

Reference Materials

Quality Documentation

- HMC Legacy PDN: PCN0811003
- Package/Assembly Qualification Test Report: LC3, LC3B, LC3C (QTR: 2014-00376 REV: 01)
- Package/Assembly Qualification Test Report: LC5, LC5A (QTR: 2014-00384 REV: 01)
- Semiconductor Qualification Test Report: BiCMOS-C (QTR: 2013-00241)

Design Resources

- HMC853 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC853 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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MICROWAVE CORPORATION v01.0614



HMC853LC3

28 GBPS, D-TYPE FLIP-FLOP w/ PROGRAMMABLE OUTPUT VOLTAGE

Typical Applications

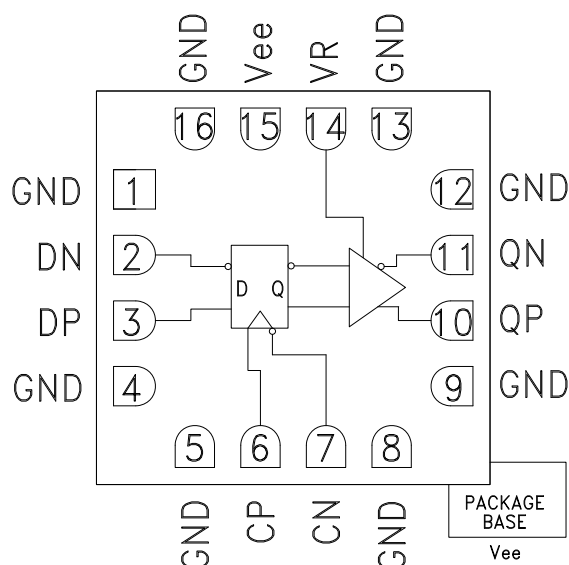
The HMC853LC3 is ideal for:

- RF ATE Applications
- Broadband Test & Measurement
- Serial Data Transmission up to 28 Gbps
- Digital Logic Systems up to 28 GHz

Features

- Differential & Single-Ended Operation
- Fast Rise and Fall Times: 15/14 ps
- Low Power Consumption: 240 mW typ.
- Programmable Differential
Output Voltage Swing: 700 - 1300 mVp-p
- Single Supply: -3.3 V
- 16 Lead Ceramic 3x3 mm SMT Package: 9 mm²

Functional Diagram



General Description

The HMC853LC3 is a D-Type Flip-Flop designed to support data transmission rates of up to 28 Gbps, and clock frequencies as high as 28 GHz. During normal operation, data is transferred to the outputs on the positive edge of the clock. Reversing the clock inputs allows for negative-edge triggered applications.

All differential inputs to the HMC853LC3 are CML and terminated on-chip with 50 Ohms to the positive supply, Vcc, and may be AC or DC coupled. The differential CML outputs are source terminated to 50 Ohms and may also be AC or DC coupled. Outputs can be connected directly to a 50 Ohm Vcc-terminated system, while DC blocking capacitors may be used if the terminating system is 50 Ohms to ground. The HMC853LC3 also features an output level control pin, VR, which allows for loss compensation or signal-level optimization. the HMC853LC3 operates from a single 3.3 V supply and is available in ROHS-compliant 3x3 mm SMT package.

Electrical Specifications, $T_A = 25^\circ\text{C}$, $V_{ee} = -3.3\text{ V}$, $VR = 0\text{ V}$

Parameter	Conditions	Min.	Typ.	Max	Units
Power Supply Voltage		-3.6	-3.3	-3.0	V
Power Supply Current			73		mA
Maximum Data Rate			28		Gbps
Maximum Clock Rate			28		GHz
Input Voltage Range		-1.5		0.5	V
Input Differential Voltage		0.1		2.0	Vp-p
Input Return Loss, Output Return Loss	Frequency <24 GHz		10		dB
Output Amplitude	Single-Ended, peak-to-peak		550		mVp-p
	Differential, peak-to-peak		1100		mVp-p
Output High Voltage			-10		mV

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

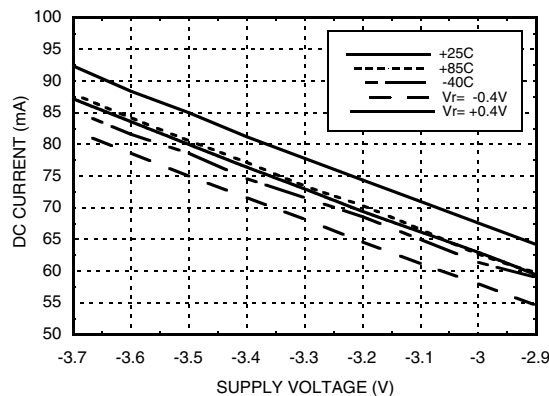
Application Support: Phone: 978-250-3343 or apps@hittite.com

28 GBPS, D-TYPE FLIP-FLOP w/ PROGRAMMABLE OUTPUT VOLTAGE

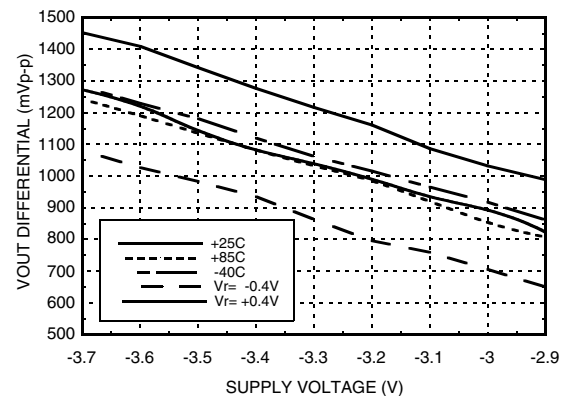
Electrical Specifications (continued)

Parameter	Conditions	Min.	Typ.	Max	Units
Output Low Voltage			-560		mV
Output Rise / Fall Time	Differential, 20% - 80%		15 / 14		ps
Output Return Loss	Frequency <24 GHz		10		dB
Random Jitter Jr	rms			0.2	ps rms
Deterministic Jitter, Jd	peak-to-peak, 2 ¹⁵ -1 PRBS input [1]		2		ps, p-p
Propagation Delay Clock to Data, td			101		ps
Clock Phase Margin	28 GHz		300		deg
Set Up Time, t _s			4		ps
Hold Time, t _h			3		ps
VR Pin Current	VR = 0.0 V		2.5		mA
VR Pin Current	VR = 0.4 V			4	mA

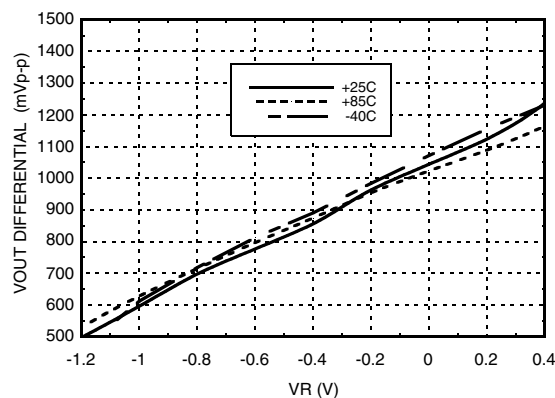
DC Current vs. Supply Voltage [1][2]



Output Differential Voltage vs. Supply Voltage [1][2]



Output Differential Voltage vs. VR [2][3]



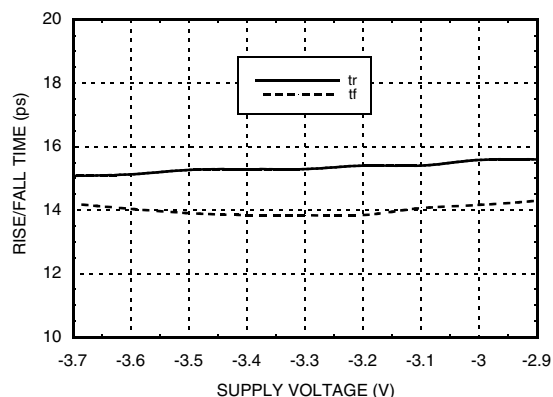
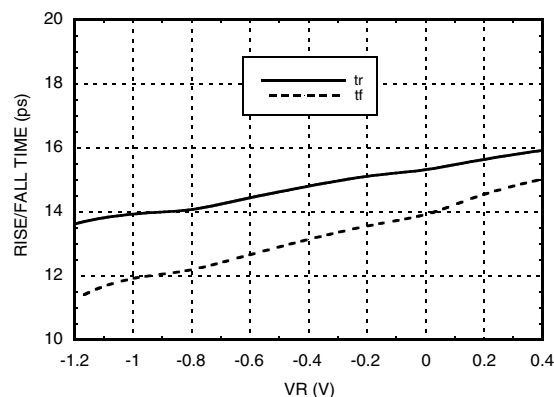
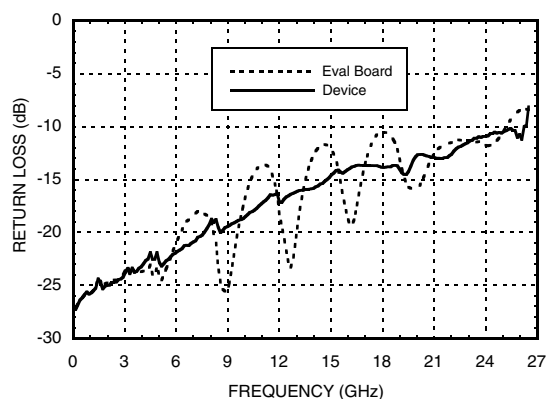
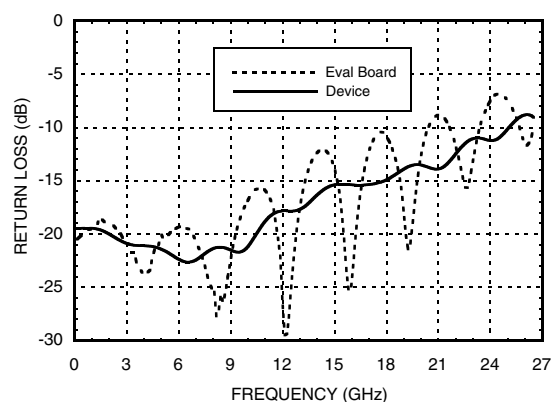
[1] VR = 0.0 V

[2] Frequency = 13 GHz

[3] Vee = -3.3 V



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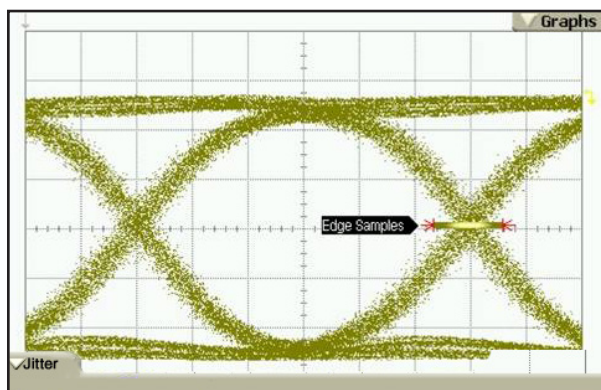
**HMC853LC3****28 GBPS, D-TYPE FLIP-FLOP
w/ PROGRAMMABLE OUTPUT VOLTAGE****Rise / Fall Time vs. Supply Voltage [1][2]****Rise / Fall Time vs. VR [2][4]****Input Return Loss vs. Frequency [1][3][4]****Output Return Loss vs. Frequency [1][3][4]**

[1] VR = 0.0 V
[4] V_{ee} = -3.3 V

[2] Frequency = 13 GHz

[3] Device measured on evaluation board with single-ended time domain gating.

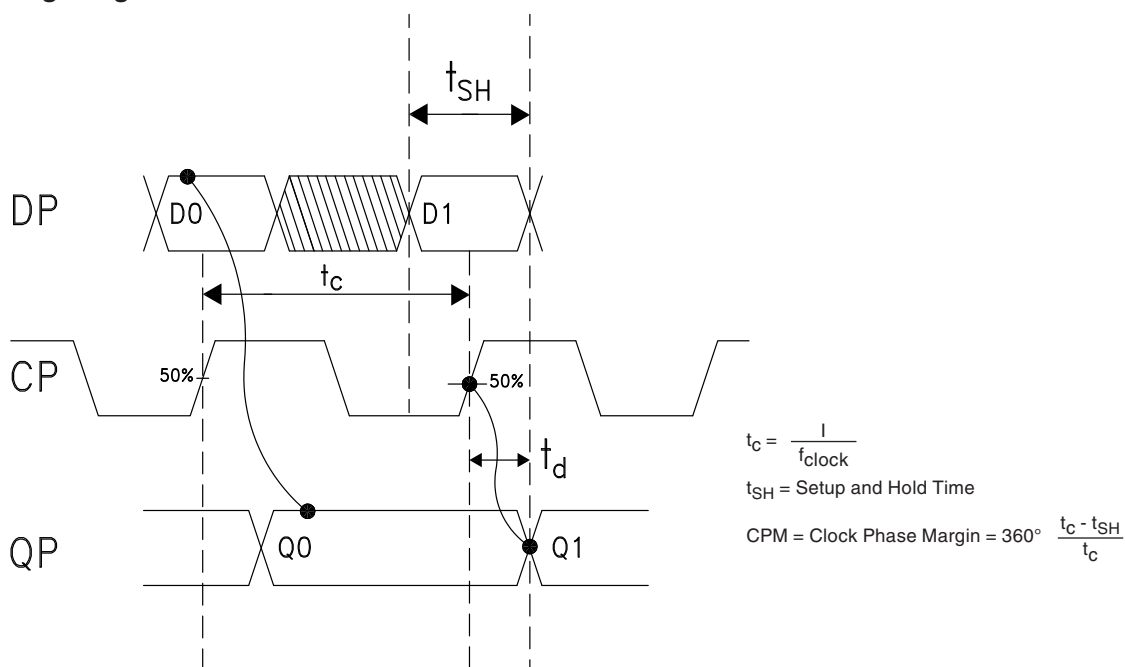
28 GBPS, D-TYPE FLIP-FLOP w/ PROGRAMMABLE OUTPUT VOLTAGE

Eye Diagram @ 25 Gbps


Parameter	Conditions
Bit Rate	24.9900 Gbps
Pattern Length	127 Bits
DJ (d-d)	2.0 ps
Vertical Scale	100 mV / div
Time Scale	6.7 ps / div

Test Conditions:

Pattern generated with a 2⁷-1 PN generator at 25 GHz. Measured using an Agilent 86100C 33 GHz DCA. Single-ended 550 mV data and 400 mV clock inputs.

Timing Diagram

Truth Table

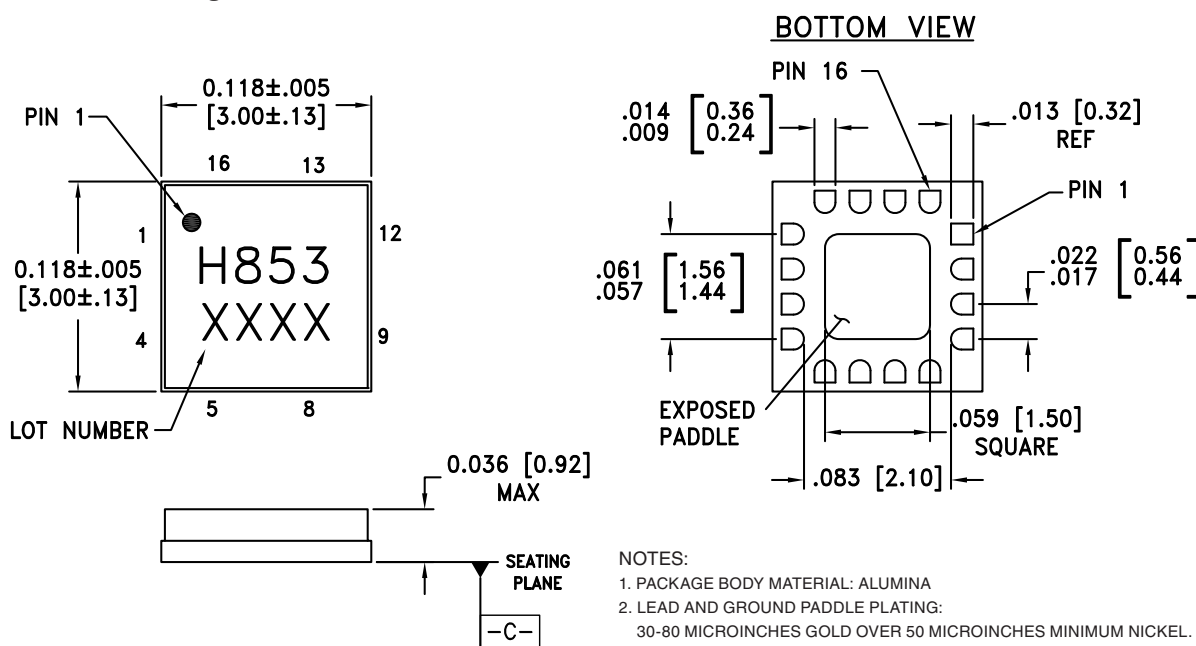
Input		Outputs
D	C	Q
L	L → H	L
H	L → H	H
Notes: D = DP - DN C = CP - CN Q = QP - QN		H - Positive Difference Voltage L - Negative Difference Voltage



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**HMC853LC3****28 GBPS, D-TYPE FLIP-FLOP
w/ PROGRAMMABLE OUTPUT VOLTAGE****Absolute Maximum Ratings**

Power Supply Voltage (Vee)	-3.75 V to +0.5 V
Input Signals	-2 V to +0.5 V
Output Signals	-1.5 V to +1 V
Continuous P _{diss} (T = 85 °C) (derate 17 mW/°C above 85 °C)	0.68 W
Thermal Resistance (R _{th(j-p)}) Worst Case Junction to Package Paddle	59 °C/W
Maximum Junction Temperature	125 °C
Storage Temperature	-65 °C to +150 °C
Operating Temperature	-40 °C to +85 °C
ESD Sensitivity (HBM)	Class 1C

**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS****Outline Drawing****NOTES:**

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING:
30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05 mm DATUM -C-
6. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
7. PADDLE MUST BE SOLDERED TO Vee.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC853LC3	Alumina, White	Gold over Nickel	MSL3 ^[1]	H853 XXXX

[1] Max peak reflow temperature of 260 °C

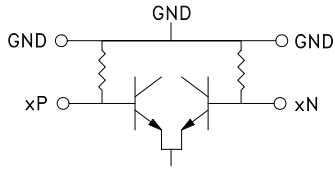
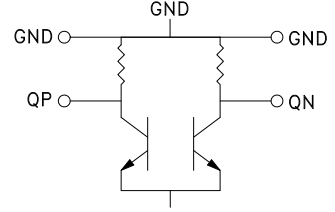
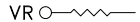
[2] 4-Digit lot number XXXX

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Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.comApplication Support: Phone: 978-250-3343 or apps@hittite.com

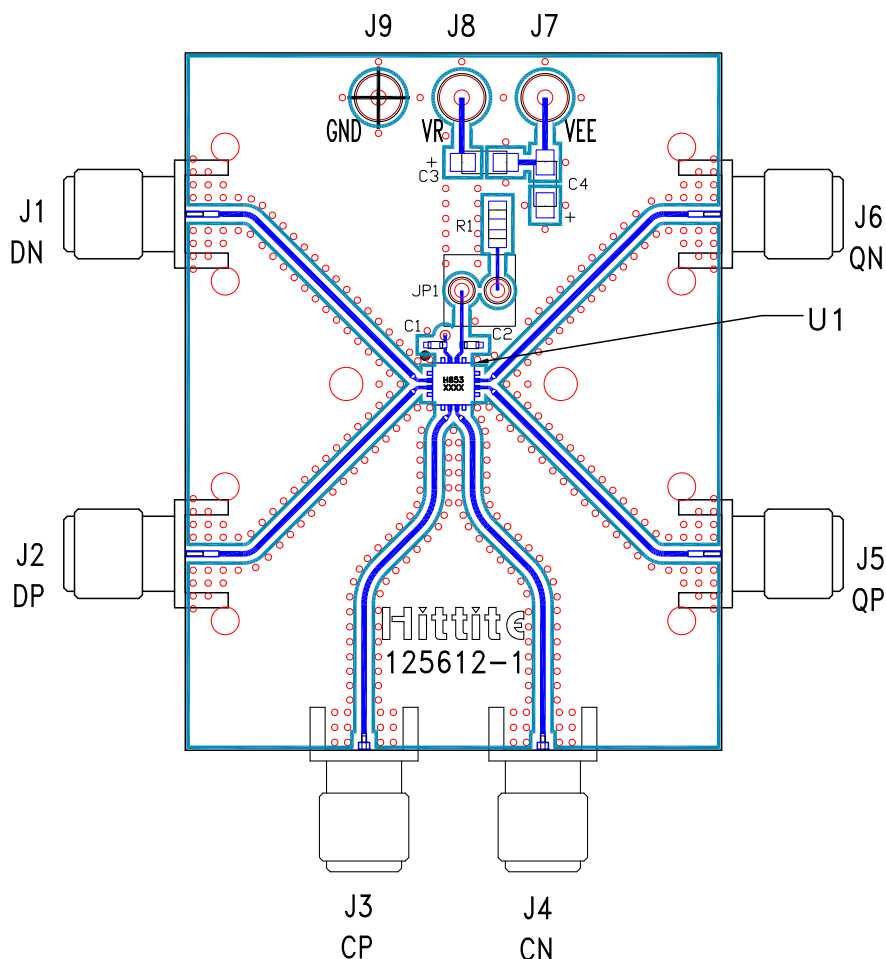
28 GBPS, D-TYPE FLIP-FLOP w/ PROGRAMMABLE OUTPUT VOLTAGE

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 5, 8, 9, 12	GND	Signal Grounds	
2, 3 6, 7	DN, DP CP, CN	Differential Data Inputs: Current Mode Logic (CML) referenced to positive supply	
10, 11	QP, QN	Differential Data Outputs: Current Mode Logic (CML) referenced to positive supply.	
13, 16	GND	Supply Ground	
14	VR	Output level control. Output level may be increased or decreased by applying a voltage to VR per "Output Differential vs. VR" plot.	
15, Package Base	Vee	This pin and the exposed paddle must be connected to the negative voltage supply.	

28 GBPS, D-TYPE FLIP-FLOP w/ PROGRAMMABLE OUTPUT VOLTAGE

Evaluation PCB



List of Materials for Evaluation PCB 125614 [1]

Item	Description
J1 - J6	PCB Mount K RF Connectors
J7 - J9	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	4.7 μ F Capacitor, Tantalum
R1	10 Ohm Resistor, 0603 Pkg.
U1	HMC853LC3 High Speed Logic, D-Type Flip-Flop
PCB [2]	125612 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. The exposed metal package base must be connected to Vee. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request. Install jumper on JP1 to short VR to GND for normal operation.

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Application Circuit

